SCCS018B - MAY 1994 - REVISED NOVEMBER 2001

- **Function, Pinout, and Drive Compatible** With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- **Edge-Rate Control Circuitry for** Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- **Matched Rise and Fall Times**
- Fully Compatible With TTL Input and **Output Logic Levels**
- CY54FCT245T
 - 48-mA Output Sink Current 12-mA Output Source Current
- CY74FCT245T
 - 64-mA Output Sink Current 32-mA Output Source Current
- 3-State Outputs

description

The 'FCT245T devices contain eight noninverting

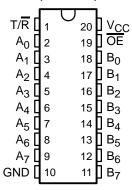
bidirectional buffers with 3-state outputs and are intended for bus-oriented applications. The transmit/receive (T/\overline{R}) input determines the direction of data flow through these bidirectional transceivers.

the A and B ports by putting them in the high-impedance state.

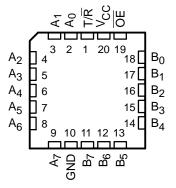
These devices are fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Transmit (active high) enables data from A ports to B ports. The output enable (\overline{OE}) , when high, disables both

CY54FCT245T . . . D PACKAGE CY74FCT245T . . . P. Q. OR SO PACKAGE (TOP VIEW)



CY54FCT245T...L PACKAGE (TOP VIEW)





PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of

ORDERING INFORMATION

TA	PAC	KAGE†	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE Marking
	QSOP - Q	Tape and reel	3.8	CY74FCT245DTQCT	FCT245D
	QSOP - Q	Tape and reel	4.1	CY74FCT245CTQCT	FCT245C
	SOIC - SO	Tube	4.1	CY74FCT245CTSOC	FCT245C
	3010 - 30	Tape and reel	4.1	CY74FCT245CTSOCT	FC1245C
	DIP – P	Tube	4.6	CY74FCT245ATPC	CY74FCT245ATPC
–40°C to 85°C	QSOP - Q	Tape and reel	4.6	CY74FCT245ATQCT	FCT245A
	SOIC - SO	Tube	4.6	CY74FCT245ATSOC	FCT245A
	3010 - 30	Tape and reel	4.6	CY74FCT245ATSOCT	FC1245A
	QSOP - Q	Tape and reel	7	CY74FCT245TQCT	FCT245
	SOIC - SO	Tube	7	CY74FCT245TSOC	FCT245
	3010 - 30	Tape and reel	7	CY74FCT245TSOCT	FC1245
	CDIP - D	Tube	4.5	CY54FCT245CTDMB	
	LCC – L	Tube	4.5	CY54FCT245CTLMB	
–55°C to 125°C	CDIP – D	Tube	4.9	CY54FCT245ATDMB	
-55 C to 125 C	LCC – L	Tube	4.9	CY54FCT245ATLMB	
	CDIP - D	Tube	7.5	CY54FCT245TDMB	
	LCC – L	Tube	7.5	CY54FCT245TLMB	

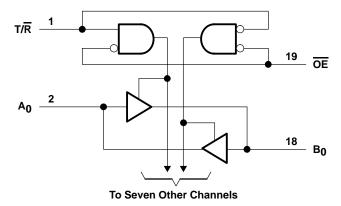
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

INP	UTS	OPERATION				
OE	T/R	UPERATION				
L	L	B data to bus A				
L	Н	A data to bus B				
Н	Χ	Z				

H = High logic level, L = Low logic level,X = Don't care, Z = High-impedancestate

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential		0.5	V to 7 V
DC input voltage range		0.5	V to $7\ V$
DC output voltage range		0.5	\mbox{V} to 7 \mbox{V}
DC output current (maximum sink current/pin)			120 mA
Package thermal impedance, θ_{JA} (see Note 1):	: P package		69°C/W
•	Q package		68°C/W
	SO package		58°C/W
Ambient temperature range with power applied	, T _A	–65°C ¹	to 135°C
Storage temperature range, T _{stq}	· · · · · · · · · · · · · · · · · · ·	–65°C ¹	to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 2)

			54FCT24	.5T	CY74FCT245T CY74FCT245AT CY74FCT245CT CY74FCT245DT			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
V _{IL}	Low-level input voltage			0.8			0.8	V
loh	High-level output current			-12			-32	mA
l _{OL}	Low-level output current			48			64	mA
TA	Operating free-air temperature	-55		125	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

CY54FCT245T, CY74FCT245T 8-BIT TRANSĆEIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER		TOT CONDITION		CY	54FCT24	I5T	CY	74FCT24	I5T	UNIT
PARAMETER	"	EST CONDITIONS	5	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII
Voice	V _{CC} = 4.5 V,	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2				V
VIK	$V_{CC} = 4.75 \text{ V},$	$I_{IN} = -18 \text{ mA}$						-0.7	-1.2	V
	$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -12 \text{ mA}$		2.4	3.3					
Voн	V _{CC} = 4.75 V	$I_{OH} = -32 \text{ mA}$					2			V
	VCC = 4.75 V	$I_{OH} = -15 \text{ mA}$					2.4	3.3		
Voi	$V_{CC} = 4.5 \text{ V},$	$I_{OL} = 48 \text{ mA}$			0.3	0.55				٧
VOL	$V_{CC} = 4.75 \text{ V},$	$I_{OL} = 64 \text{ mA}$						0.3	0.55	V
V_{hys}	All inputs				0.2			0.2		V
1.	$V_{CC} = 5.5 \text{ V},$	VIN = VCC				5				μА
lį	$V_{CC} = 5.25 \text{ V},$	VIN = VCC							5	μΑ
1	$V_{CC} = 5.5 \text{ V},$	$V_{1N} = 2.7 \text{ V}$				±1				μА
ΊΗ	$V_{CC} = 5.25 \text{ V},$	$V_{1N} = 2.7 \text{ V}$							±1	μΑ
1	$V_{CC} = 5.5 \text{ V},$	$V_{IN} = 0.5 V$				±1				μΑ
IIL	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 0.5 V$							±1	μΑ
lozu	$V_{CC} = 5.5 \text{ V},$	V _{OUT} = 2.7 V				10				μΑ
lozh	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 2.7 V							10	μΑ
lozi	$V_{CC} = 5.5 \text{ V},$	$V_{OUT} = 0.5 V$				-10				μΑ
lozL	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 0.5 V							-10	μΑ
los‡	$V_{CC} = 5.5 \text{ V},$	$V_{OUT} = 0 V$		-60	-120	-225				mA
ios+	$V_{CC} = 5.25 \text{ V},$	$V_{OUT} = 0 V$					-60	-120	-225	ША
l _{off}	$V_{CC} = 0 V$	V _{OUT} = 4.5 V				±1			±1	μΑ
loo	$V_{CC} = 5.5 \text{ V},$	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2				m ^
Icc	V _{CC} = 5.25 V,	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.1	0.2	mA
	$V_{CC} = 5.5 \text{ V}, V_{IN} = 3.$	4 V\$, f ₁ = 0, Outp	uts open		0.5	2				
ΔICC	V _{CC} = 5.25 V, V _{IN} = 3	3.4 V§, f ₁ = 0, Out	puts open					0.5	2	mA
la an ¶	$V_{CC} = 5.5 \text{ V}, One inpute Outputs open, T/R or VIN \leq 0.2 \text{ V} or V_{IN} \geq 0.2 \text{ V}$	OE = GND and	% duty cycle,		0.06	0.12				mA/
ICCD¶	$V_{CC} = 5.25 \text{ V}, \text{ One inj}$ Outputs open, T/\overline{R} or $V_{IN} \le 0.2 \text{ V}$ or $V_{IN} \ge 0.2 \text{ V}$	OE = GND and	0% duty cycle,					0.06	0.12	MHz

 $[\]overline{\dagger}$ Typical values are at V_{CC} = 5 V, T_A = 25°C.



^{\$\}frac{1}{2}\$ Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

[§] Per TTL-driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND

This parameter is derived for use in total power-supply calculations.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

DADAMETER		CY	54FCT2	45T	CY	74FCT24	15T	UNIT		
PARAMETER		TEST CONDITION		MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT
			$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4				
	V _{CC} = 5.5 V,	at f ₁ = 10 MHz at 50% duty cycle	V _{IN} = 3.4 V or GND		1.2	3.4				
	T/R or OE = GND	Outputs open, T/R or OE = GND Eight bits switching at f ₁ = 2.5 MHz at 50% duty cycle	$V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC} - 0.2 V$		1.3	2.6				
IC#			V _{IN} = 3.4 V or GND		3.3	10.6				mA
IC.		One bit switching at f ₁ = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.7	1.4	IIIA
	VCC = 5.25 V,	at 50% duty cycle	V _{IN} = 3.4 V or GND					1.2	3.4	
	Outputs open, T/R or OE = GND	Eight bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2V$ or $V_{IN} \ge V_{CC} - 0.2 V$					1.3	2.6	
		at 50% duty cycle	V _{IN} = 3.4 V or GND					3.3	10.6	
Ci					5	10		5	10	pF
Co					9	12		9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

Where:

I_C = Total supply current

ICC = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input (V_{IN} = 3.4 V)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

f₀ = Clock frequency for registered devices, otherwise zero

f₁ = Input signal frequency

 N_1 = Number of inputs changing at f_1

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I_{CC} formula.



 $^{^{\#}}$ IC = ICC + \triangle ICC \times DH \times NT + ICCD (f₀/2 + f₁ \times N₁)

CY54FCT245T, CY74FCT245T 8-BIT TRANSCEIVERS WITH 3-STATE OUTPUTS SCCS018B – MAY 1994 – REVISED NOVEMBER 2001

switching characteristics over operating free-air temperature range (see Figure 1)

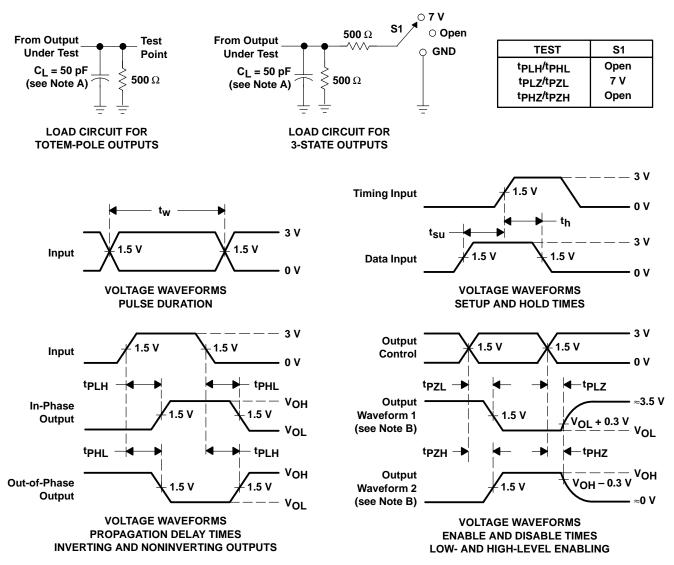
PARAMETER	FROM	то	CY54FC	CY54FCT245T		CY54FCT245AT		CY54FCT245CT	
PARAIVIETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	A or B	B or A	1.5	7.5	1.5	4.9	1.5	4.5	no
^t PHL	AUIB	BULA	1.5	7.5	1.5	4.9	1.5	4.5	ns
^t PZH	OE or T/R	A == D	1.5	10	1.5	6.5	1.5	6.2	20
^t PZL	OE 01 1/K	A or B	1.5	10	1.5	6.5	1.5	6.2	ns
^t PHZ	OE or T/R	A - : D	1.5	10	1.5	6	1.5	5.2	no
^t PLZ	OE OF 1/R	A or B	1.5	10	1.5	6	1.5	5.2	ns

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER FROM		то	CY74FCT245T		CY74FCT245AT		CY74FCT245CT		CY74FCT245DT		UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	A or B	B or A	1.5	7	1.5	4.6	1.5	4.1	1.5	3.8	20
t _{PHL}	AUB	BULA	1.5	7	1.5	4.6	1.5	4.1	1.5	3.8	ns
^t PZH	OE or T/R	A or B	1.5	9.5	1.5	6.2	1.5	5.8	1.5	5	nc
t _{PZL}	OE 01 1/K	AOIB	1.5	9.5	1.5	6.2	1.5	5.8	1.5	5	ns
^t PHZ	OE or T/R	A or B	1.5	7.5	1.5	5	1.5	4.8	1.5	4.3	nc
t _{PLZ}	OE OF 1/K	AUID	1.5	7.5	1.5	5	1.5	4.8	1.5	4.3	ns



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
5962-9221401M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9221401MRA	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9221403M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9221403MRA	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9221405M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9221405MRA	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CY54FCT245ATDMB	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CY54FCT245CTLMB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
CY54FCT245TLMB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
CY74FCT245ATPC	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT245ATPCE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CY74FCT245ATQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245ATQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245ATQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245ATSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245ATSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245ATSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245ATSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245ATSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245ATSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245CTQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245CTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245CTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245CTSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245CTSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245CTSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245CTSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245CTSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245CTSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM





.com 9-Oct-2007

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finisl	n MSL Peak Temp ⁽³⁾
						no Sb/Br)		
CY74FCT245DTQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245DTQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245DTQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245TQCT	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245TQCTE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245TQCTG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
CY74FCT245TSOC	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245TSOCE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245TSOCG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245TSOCT	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245TSOCTE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CY74FCT245TSOCTG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

9-Oct-2007

In no event shall TI's liability ari	sing out of such information	on avecad the total nu	rehace price of the TI pe	art(s) at issue in this d	ocument cold by T
In no event shall TI's liability aris to Customer on an annual basis	Sing out of Such information	on exceed the total pul	chase plice of the 11 pa	art(s) at issue in this d	ocument sold by 11





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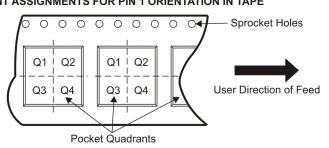
TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT245ATQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT245ATSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CY74FCT245CTQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT245CTSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
CY74FCT245DTQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT245TQCT	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT245TSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT245ATQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT245ATSOCT	SOIC	DW	20	2000	346.0	346.0	41.0
CY74FCT245CTQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT245CTSOCT	SOIC	DW	20	2000	346.0	346.0	41.0
CY74FCT245DTQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT245TQCT	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
CY74FCT245TSOCT	SOIC	DW	20	2000	346.0	346.0	41.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

FK (S-CQCC-N**)

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004



DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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